



Development of Low Dark-count Photodetectors

and Mid-IR Light Sources



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Outline



Development of low dark-count photodetectors

 Near infrared PMT and hybrid photodetectors
 Collaboration with quantum measurement group Hokkaido Univ.

Mid-IR light sources in Molecular Finger Print Region

Intrinsic linewidth of quantum cascade laser
Broad-gain quantum cascade laser
Low power consumption: short cavity QCL
THz laser based on indirect pump scheme



Development of Low Dark-count Photodetectors

and

Low Power Consumption Mid-IR Light Source



Motivation

For the practical application of quantum cryptography, quantum key distribution (QKD) for 200km should be achieved by using the detector under practical temperature operation.

For 200km QKD, 1550nm wavelength detector must have high sensitivity and lower dark counts.

Specifications Required for 200km QKD

- Wavelength $1.55 \mu m$ (for optical fiber)
- · Sensitivity > ~ 10 %
- · Dark counts $< \sim 100$ cps
- Operating temp. > 173 K (Thermoelectric cooler)
- High speed response > 1 GHz



Summary of Last Year's Report

Designed NIR-PMT with New Cathode Structure Confirmed •Quantum efficiency: 7 % (at 1550 nm)
•Dark counts: 5 cps (at -75 °C)



200 km Quantum Key Distribution 620 bps (calculation)

• Attempt to evaluate the PMT mounted on the thermoelectric cooler.



Results of The This Year

- Developed a new type PMT assembled with thermoelectric cooler and evaluated the detector characteristics.
- Designed a Near-Infrared Hybrid Photo-detector (HPD) for higher speed detection and confirmed preliminary operation.



Development of NIR-PMT Module

• NIR-PMT Module Performance • maximum cooling temperature $-87^{\circ}C$ optical coupling efficiency •Q.E. 3.6 % (@1550nm) dark counts 77cps

•Q.E. of PMT must be improved. Optimization of photocathode activation and optical coupling system

Near Infrared Hybrid Photodetector (NIR-HPD)

Design for e-beam focusing!

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Confirmation of Cathode Operation

Schedule

Next Year

- Evaluation of PMT module in practical measurement in quantum information research.
- Realization of high spec operation of NIR-HPD.
 - Optimization of the photocathode activation
 - Development of thermoelectric cooler for NIR-HPD

Future

• Single Photon Detection in Mid-IR region by Up-Conversion .

Development of Low Dark-count Photodetector

and Mid-IR Light Sources

Measuring frequency noise and intrinsic linewidth of a room-temperature DFB quantum cascade laser

Quantum Cascade Laser (QCL)

S. Bartalini,^{1,2,*} S. Borri,^{1,2} I. Galli,^{1,2} G. Giusfredi,^{1,2} D. Mazzotti,^{1,2} T. Edamura,³ N. Akikusa,³ M. Yamanishi,³ and P. De Natale^{1,2}

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[Opt. Express <u>19</u> 17996 (2011).]

$$\mathcal{F} = \frac{1}{4\pi} \left(1 + \alpha_c^2 \left(\frac{\tau_t}{\tau_r} \beta \right) \gamma / \left(I_0 / I_{th} - 1 \right) \right)$$

[M. Yamanishi et al., IEEE JQE <u>44</u> 12 (2008).]

mid-IR領域: <1 kHz

Experimental Proof

Attractive application fields

Cooling of molecular ro-vibrationsMid-IR frequency comb

Supporting the Italian group

Device Performances of DAU-MS QCL

■Broad band EL (Gain) spectra → linewidth : $\Delta \lambda / \lambda_0 \sim 40\%$ (300] ■High output power → over 500mW : CW / 300K

Tuned with Littrow configuration in room temperature

□Pulsed operation $\rightarrow \Delta \lambda / \lambda_0 \sim 22\% (321 \text{cm}^{-1})$ □CW operation $\rightarrow \Delta \lambda / \lambda_0 \sim 17\% (248 \text{cm}^{-1})$

For Low Power Consumption: Short-Cavity

I-L Properties : L=200 μ m

Typical : 300mA (L=3mm)

Single Mode Spectra : $L=200 \,\mu \,\mathrm{m} \, L/(\lambda_0 / n) = 75$

InGaAs indirect pumping THz-laser

lattice matched InGaAs/InAlAs/InP system 140-repetition **20**/89/7/121/10/119/18/210/14/118_(Angstrom)

$$\begin{array}{l} E_{43} \sim 35 \text{ meV} & \tau_{43} = 0.56 \text{ ps} \\ E_{32} \sim 15 \text{ meV} & \tau_{42} = 7.5 \text{ ps} \\ Z_{32} \sim 4.3 \text{ nm} & \tau_{42} = 21 \text{ ps} \\ N_{\text{inj}} \sim 6 \times 10^{16} \text{ (cm}^{-3}) \end{array}$$

Metal-Metal waveguide (Au/Ti-Au/Ti)

diagonal transition LO-phonon depopulation with two well injector

I-L and I-V characteristics of IDP THz laser

Summary and Future Work

Summary

OIntrinsic narrow linewidth : ~260Hz

ORealization of High-performance broad-gain QCL based on DAU design : $\Delta \lambda / \lambda 0 \sim 40\%$ (tuning of 17% in cw)

Osingle mode lasing in short cavity (L=200 μ m) QCL low power consumption : threshold current of 90mA at 300K

OTHz-QCL based on IDP design observation of lasing up to 83K

Future Work

OResearch of the limit of linewidth: a few HZ QCL with External Cavity

OVery low power consumption Mid-IR light sources Polariton Device with Short Cavity

OTEC (~250 K) operation of THz QCLs Optimization of Active Region based on IDP design

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